

Description

The R1WV3216R Series is a family of low voltage 32-Mbit static RAMs organized as 2097152-words by 16-bit, fabricated by Renesas's high-performance 0.15um CMOS and TFT technologies.

The R1WV3216R Series is suitable for memory applications where a simple interfacing , battery operating and battery backup are the important design objectives.

The R1WV3216R Series is made by stacked-micro-package technology and two chips of 16Mbit Advanced LPSRAMs are assembled in one package.

The R1WV3216R Series is packaged in a 52pin micro thin small outline mount device[μTSOP / 10.79mm x 10.49mm with the pin-pitch of 0.4mm] or a 48balls fine pitch ball grid array [f-BGA / 7.5mmx8.5mm with the ball-pitch of 0.75mm and 6x8 array] . It gives the best solution for a compaction of mounting area as well as flexibility of wiring pattern of printed circuit boards.

Features

- Single 2.7-3.6V power supply
- Small stand-by current:4μA (3.0V, typ.)
- Data retention supply voltage =2.0V
- No clocks, No refresh
- All inputs and outputs are TTL compatible.
- Easy memory expansion by CS1#, CS2, LB# and UB#
- Common Data I/O
- Three-state outputs: OR-tie capability
- OE# prevents data contention on the I/O bus
- Process technology: 0.15um CMOS

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| Ordering Information |
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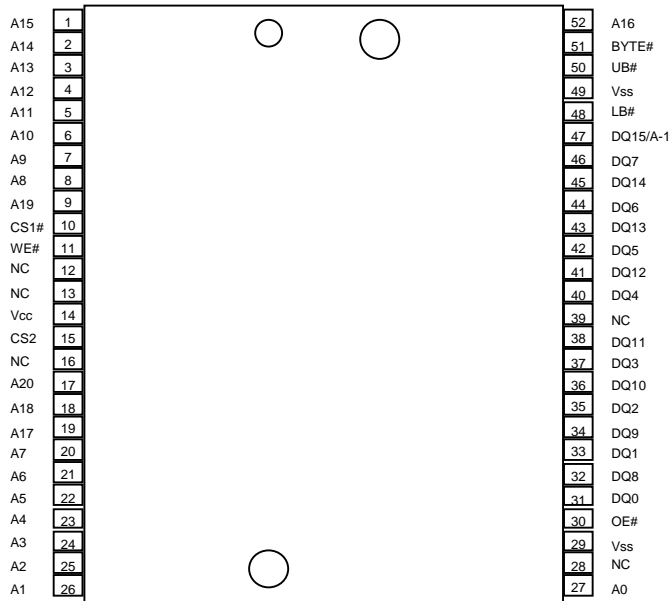
| Type No. | Access time | Package |
|-----------------|-------------|---|
| R1WV3216RSD-7S% | 70 ns | 350-mil 52-pin plastic μ - TSOP(II) (normal-bend type) (52PTG) |
| R1WV3216RSD-8S% | 85 ns | |
| R1WV3216RBG-7S% | 70 ns | 7.5mmx8.5mm f-BGA 0.75mm pitch 48ball |
| R1WV3216RBG-8S% | 85 ns | |

% - Temperature version; see table below

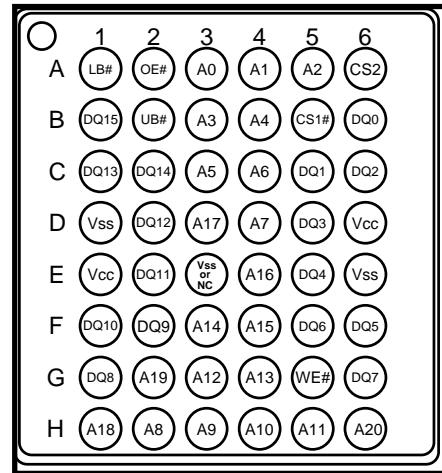
| % | Temperature Range |
|---|-------------------|
| R | 0 ~ +70 °C |
| I | -40 ~ +85 °C |

Pin Arrangement

52-pin μ TSSOP



48-pin fBGA



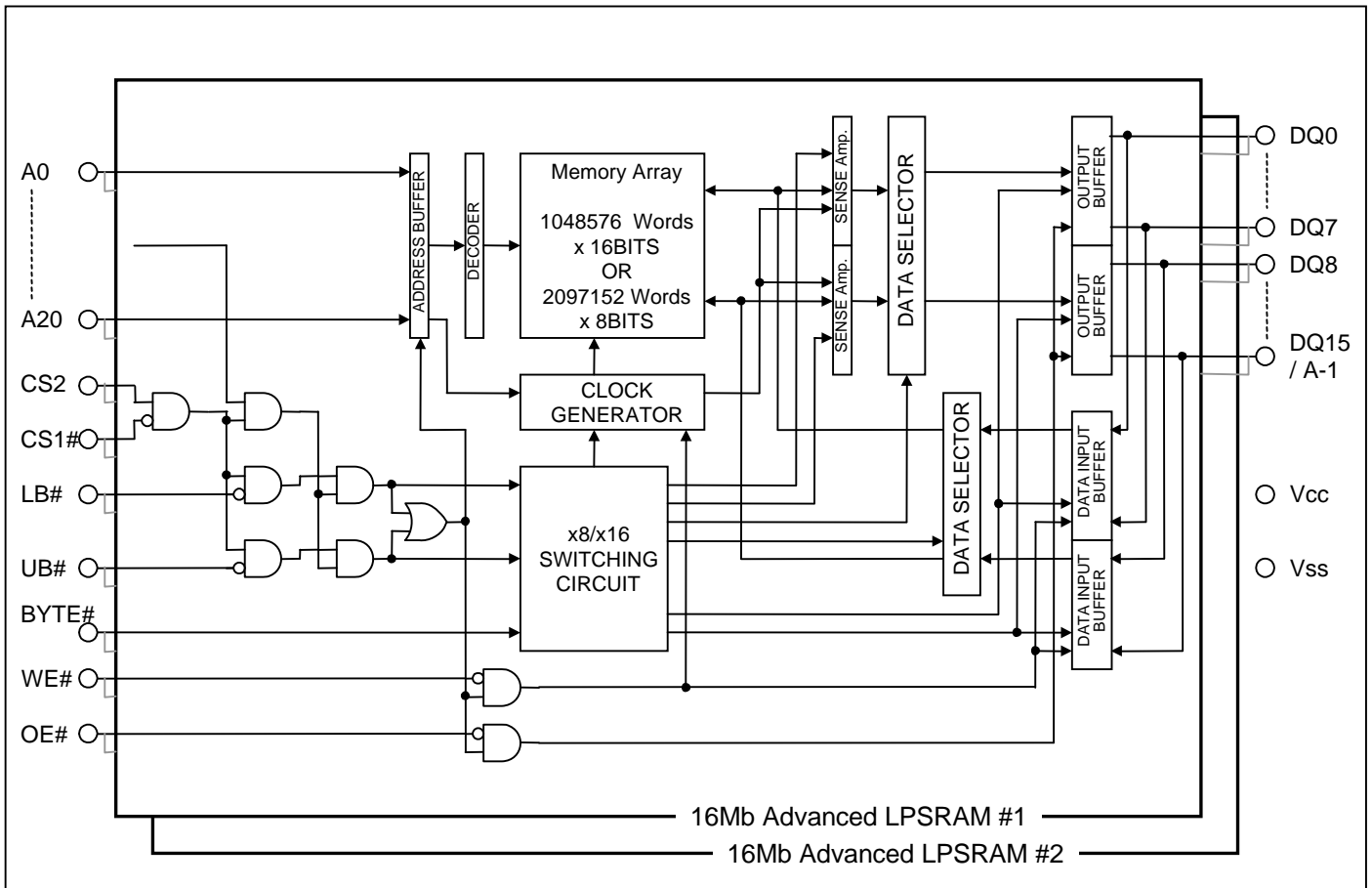
(Top view)

Pin Description

| Pin name | Function |
|--------------|-----------------------------|
| A0 to A20 | Address input (Word mode) |
| A-1 to A20 | Address input (Byte mode) |
| DQ 0 to DQ15 | Data input/output |
| CS1# & CS2 | Chip select |
| WE# | Write enable |
| OE# | Output enable |
| LB# | Lower byte select |
| UB# | Upper byte select |
| Vcc | Power supply |
| Vss | Ground |
| BYTE# | Byte (x8 mode) enable input |
| NC | Non connection |

Note: Byte Mode is supported by only 52-pin μ TSSOP type.

Block Diagram



Note: BYTE# pin is supported by only 52-pin μ TSOP type.

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| Operating Table |
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| CS1# | CS2 | BYTE# | LB# | UB# | WE# | OE# | DQ0-7 | DQ8-14 | DQ15 | Operation |
|------|-----|-------|-----|-----|-----|-----|--------|--------|--------|----------------------|
| H | X | X | X | X | X | X | High-Z | High-Z | High-Z | Stand by |
| X | L | X | X | X | X | X | High-Z | High-Z | High-Z | Stand by |
| X | X | H | H | H | X | X | High-Z | High-Z | High-Z | Stand by |
| L | H | H | L | H | L | X | Din | High-Z | High-Z | Write in lower byte |
| L | H | H | L | H | H | L | Dout | High-Z | High-Z | Read from lower byte |
| L | H | X | X | X | H | H | High-Z | High-Z | High-Z | Output disable |
| L | H | H | H | L | L | X | High-Z | Din | Din | Write in upper byte |
| L | H | H | H | L | H | L | High-Z | Dout | Dout | Read from upper byte |
| L | H | H | L | L | L | X | Din | Din | Din | Write |
| L | H | H | L | L | H | L | Dout | Dout | Dout | Read |
| L | H | L | L | L | L | X | Din | High-Z | A-1 | Write |
| L | H | L | L | L | H | L | Dout | High-Z | A-1 | Read |

Note 1. H:VIH L:VIL X: VIH or VIL

2. BYTE# pin is supported by only 52-pin μ TSOP type. When apply BYTE# ="L" , please assign LB#=UB#="L".

| |
|---------------------------------|
| Absolute Maximum Ratings |
|---------------------------------|

| Parameter | Symbol | Value | Unit | |
|--|-------------------|---|------------|----|
| Power supply voltage relative to Vss | Vcc | -0.5 to +4.6 | V | |
| Terminal voltage on any pin relation toVss | V _T | -0.5* ¹ to Vcc+0.3* ² | V | |
| Power dissipation | P _T | 0.7 | W | |
| Operation temperature | T _{opr} | R ver. * ³ | 0 to +70 | °C |
| | | I ver. * ³ | -40 to +85 | °C |
| Storage temperature | T _{stg} | -65 to +150 | °C | |
| Storage temperature range under bias | T _{bias} | R ver. * ³ | 0 to +70 | °C |
| | | I ver. * ³ | -40 to +85 | °C |

Note 1: -2.0V in case of AC (Pulse width \leq 30ns)

2: Maximum voltage is +4.6V

3: Temperature range depends on R/I-version. Please see table on page 2.

Recommended Operating Conditions

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Note | |
|---------------------------|-----------------|----------------|------|----------------------|------|------|---|
| Supply voltage | V _{CC} | 2.7 | 3.0 | 3.6 | V | | |
| | V _{SS} | 0 | 0 | 0 | V | | |
| Input high voltage | V _{IH} | 2.4 | - | V _{CC} +0.2 | V | | |
| Input low voltage | V _{IL} | -0.2 | - | 0.4 | V | 1 | |
| Ambient temperature range | R ver. | T _a | 0 | - | +70 | °C | 2 |
| | I ver. | | -40 | - | +85 | °C | 2 |

Note 1. -2.0V in case of AC (Pulse width ≤ 30ns)

2. Ambient temperature range depends on R/I-version. Please see table on page 2.

DC Characteristics

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test conditions ^{*3} |
|---------------------------|------------------|------|--------|------|------|--|
| Input leakage current | I _{LI} | - | - | 1 | μA | V _{in} =V _{SS} to V _{CC} |
| Output leakage current | I _{LO} | - | - | 1 | μA | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, CS1# = V _{IH} or CS2 = V _{IL} or OE# = V _{IH} or WE# = V _{IL} or LB# = UB# = V _{IH} , V _{I/O} =V _{SS} to V _{CC} |
| Average operating current | I _{CC1} | - | 30 *1 | 55 | mA | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, Min. cycle, duty =100% I I/O = 0 mA, CS1# = V _{IL} , CS2 = V _{IH} Others = V _{IH} / V _{IL} |
| | I _{CC2} | - | 3 *1 | 8 | mA | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, Cycle time = 1 μs, I I/O = 0 mA, CS1# ≤ 0.2V, CS2 ≥ V _{CC} -0.2V V _{IH} ≥ V _{CC} -0.2V, V _{IL} ≤ 0.2V, duty=100% |
| Standby current | I _{SB} | - | 0.1 *1 | 0.3 | mA | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, CS2 = V _{IL} |
| Standby current | I _{SB1} | - | 4 *1 | 12 | μA | ~+25°C V _{in} ≥ 0V, BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, |
| | | - | 7 *2 | 24 | μA | ~+40°C (1) 0V ≤ CS2 ≤ 0.2V or (2) CS2 ≥ V _{CC} -0.2V, CS1# ≥ V _{CC} -0.2V or |
| | | - | - | 50 | μA | ~+70°C (3) LB# = UB# ≥ V _{CC} -0.2V, CS2 ≥ V _{CC} -0.2V, CS1# ≤ 0.2V |
| | | - | - | 80 | μA | ~+85°C Average value |
| Output high voltage | V _{OH} | 2.4 | - | - | V | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, I _{OH} = -1mA |
| Output Low voltage | V _{OL} | - | - | 0.4 | V | BYTE# ≥ V _{CC} -0.2V or BYTE# ≤ 0.2V, I _{OL} = 2mA |

Note 1. Typical parameter indicates the value for the center of distribution at V_{CC}=3.0V (T_a= 25°C), and not 100% tested.

2. Typical parameter indicates the value for the center of distribution at V_{CC}=3.0V (T_a= 40°C), and not 100% tested.

3. BYTE# pin is supported by only 52-pin μTSSOP type.

Capacitance

(Ta = +25°C, f = 1MHz)

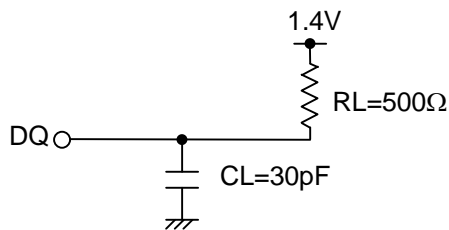
| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test conditions | Note |
|----------------------------|--------|------|------|------|------|-----------------|------|
| Input capacitance | C in | - | - | 20 | pF | V in = 0V | 1 |
| Input / output capacitance | C I/O | - | - | 20 | pF | V I/O = 0V | 1 |

Note 1. This parameter is sampled and not 100% tested.

AC Characteristics

Test Conditions (Vcc=2.7~3.6V, Ta = 0~+70°C / -40~+85°C *)

- Input pulse levels: VIL= 0.4V, VIH=2.4V
- Input rise and fall time : 5ns
- Input and output timing reference levels : 1.4V
- Output load : See figures (Including scope and jig)



Note: Temperature range depends on R/I-version. Please see table on page 2.

Read Cycle

| Parameter | Symbol | R1WV3216R**-7S | | R1WV3216R**-8S | | Unit | Notes |
|------------------------------------|------------|----------------|------|----------------|------|------|-------|
| | | Min. | Max. | Min. | Max. | | |
| Read cycle time | t_{RC} | 70 | - | 85 | - | ns | |
| Address access time | t_{AA} | - | 70 | - | 85 | ns | |
| Chip select access time | t_{ACS1} | - | 70 | - | 85 | ns | |
| | t_{ACS2} | - | 70 | - | 85 | ns | |
| Output enable to output valid | t_{OE} | - | 35 | - | 45 | ns | |
| Output hold from address change | t_{OH} | 10 | - | 10 | - | ns | |
| LB#,UB# access time | t_{BA} | - | 70 | - | 85 | ns | |
| Chip select to output in low-Z | t_{CLZ} | 10 | - | 10 | - | ns | 2,3 |
| LB#,UB# enable to low-Z | t_{BLZ} | 5 | - | 5 | - | ns | 2,3 |
| Output enable to output in low-Z | t_{OLZ} | 5 | - | 5 | - | ns | 2,3 |
| Chip deselect to output in high-Z | t_{CHZ1} | 0 | 25 | 0 | 30 | ns | 1,2,3 |
| | t_{CHZ2} | 0 | 25 | 0 | 30 | ns | 1,2,3 |
| LB#,UB# disable to high-Z | t_{BHZ} | 0 | 25 | 0 | 30 | ns | 1,2,3 |
| Output disable to output in high-Z | t_{OHZ} | 0 | 25 | 0 | 30 | ns | 1,2,3 |

Write Cycle

| Parameter | Symbol | R1WV3216R**-7S | | R1WV3216R**-8S | | Unit | Notes |
|------------------------------------|-----------|----------------|------|----------------|------|------|-------|
| | | Min. | Max. | Min. | Max. | | |
| Write cycle time | t_{WC} | 70 | - | 85 | - | ns | |
| Address valid to end of write | t_{AW} | 65 | - | 70 | - | ns | |
| Chip selection to end of write | t_{CW} | 65 | - | 70 | - | ns | 5 |
| Write pulse width | t_{WP} | 55 | - | 60 | - | ns | 4 |
| LB#,UB# valid to end of write | t_{BW} | 65 | - | 70 | - | ns | |
| Address setup time | t_{AS} | 0 | - | 0 | - | ns | 6 |
| Write recovery time | t_{WR} | 0 | - | 0 | - | ns | 7 |
| Data to write time overlap | t_{DW} | 35 | - | 40 | - | ns | |
| Data hold from write time | t_{DH} | 0 | - | 0 | - | ns | |
| Output active from end of write | t_{OW} | 5 | - | 5 | - | ns | 2 |
| Output disable to output in high-Z | t_{OHZ} | 0 | 25 | 0 | 30 | ns | 1,2 |
| Write to output in high-Z | t_{WHZ} | 0 | 25 | 0 | 30 | ns | 1,2 |

Byte Enable (supported by only 52-pin μ TSOP)

| Parameter | Symbol | R1WV3216R**-7S | | R1WV3216R**-8S | | Unit | Notes |
|--------------------|----------|----------------|------|----------------|------|------|-------|
| | | Min. | Max. | Min. | Max. | | |
| Byte setup time | t_{BS} | 5 | - | 5 | - | ms | |
| Byte recovery time | t_{BR} | 5 | - | 5 | - | ms | |

Note 1. t_{CHZ} , t_{OHZ} , t_{WHZ} and t_{BHZ} are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.

2. This parameter is sampled and not 100% tested.

3. AT any given temperature and voltage condition, t_{HZ} max is less than t_{LZ} min both for a given device and from device to device.

4. A write occurs during the overlap of a low CS1#, a high CS2, a low WE# and a low LB# or a low UB#.

A write begins at the latest transition among CS1# going low, CS2 going high, WE# going low and LB# going low or UB# going low .

A write ends at the earliest transition among CS1# going high, CS2 going low, WE# going high and LB# going high or UB# going high. t_{WP} is measured from the beginning of write to the end of write.

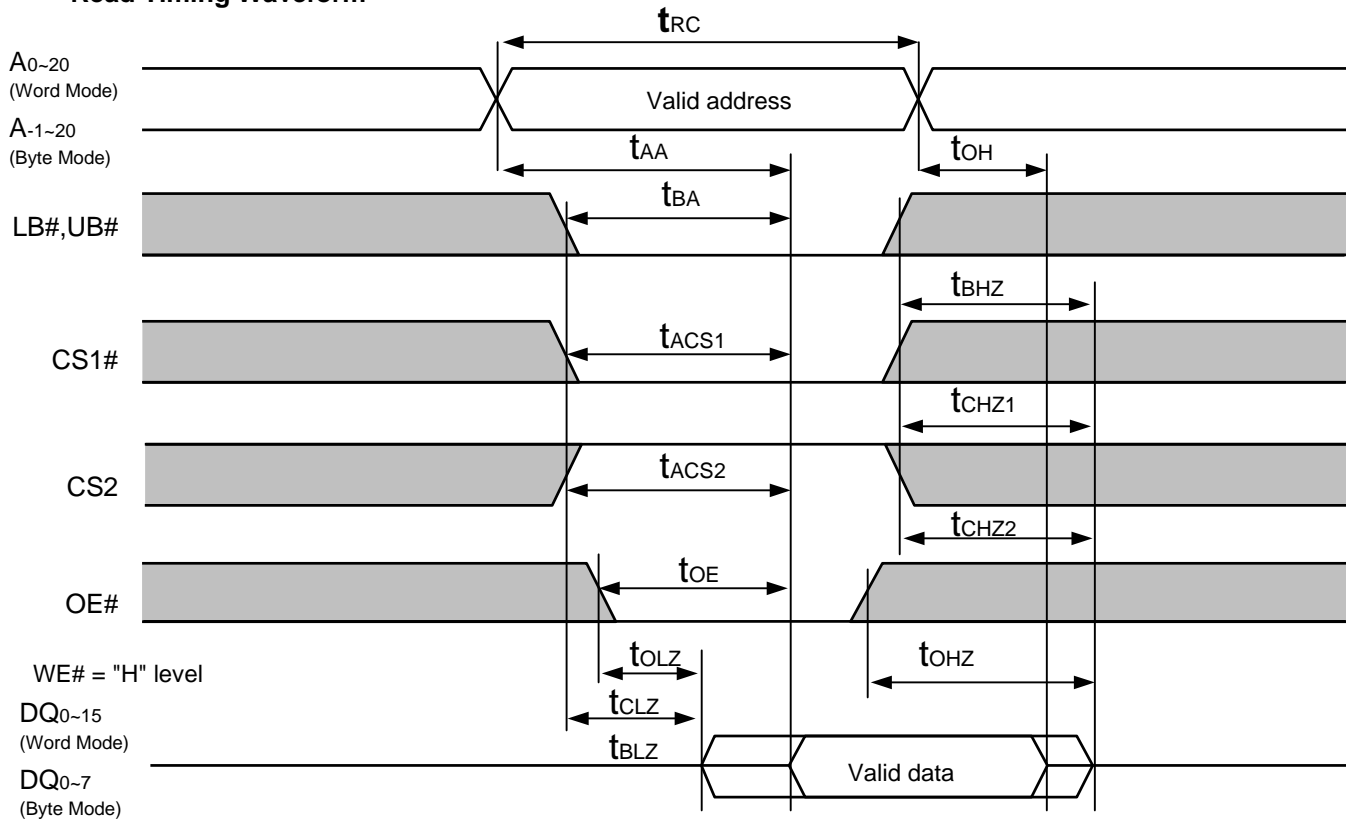
5. t_{CW} is measured from the later of CS1# going low or CS2 going high to end of write.

6. t_{AS} is measured the address valid to the beginning of write.

7. t_{WR} is measured from the earliest of CS1# or WE# going high or CS2 going low to the end of write cycle.

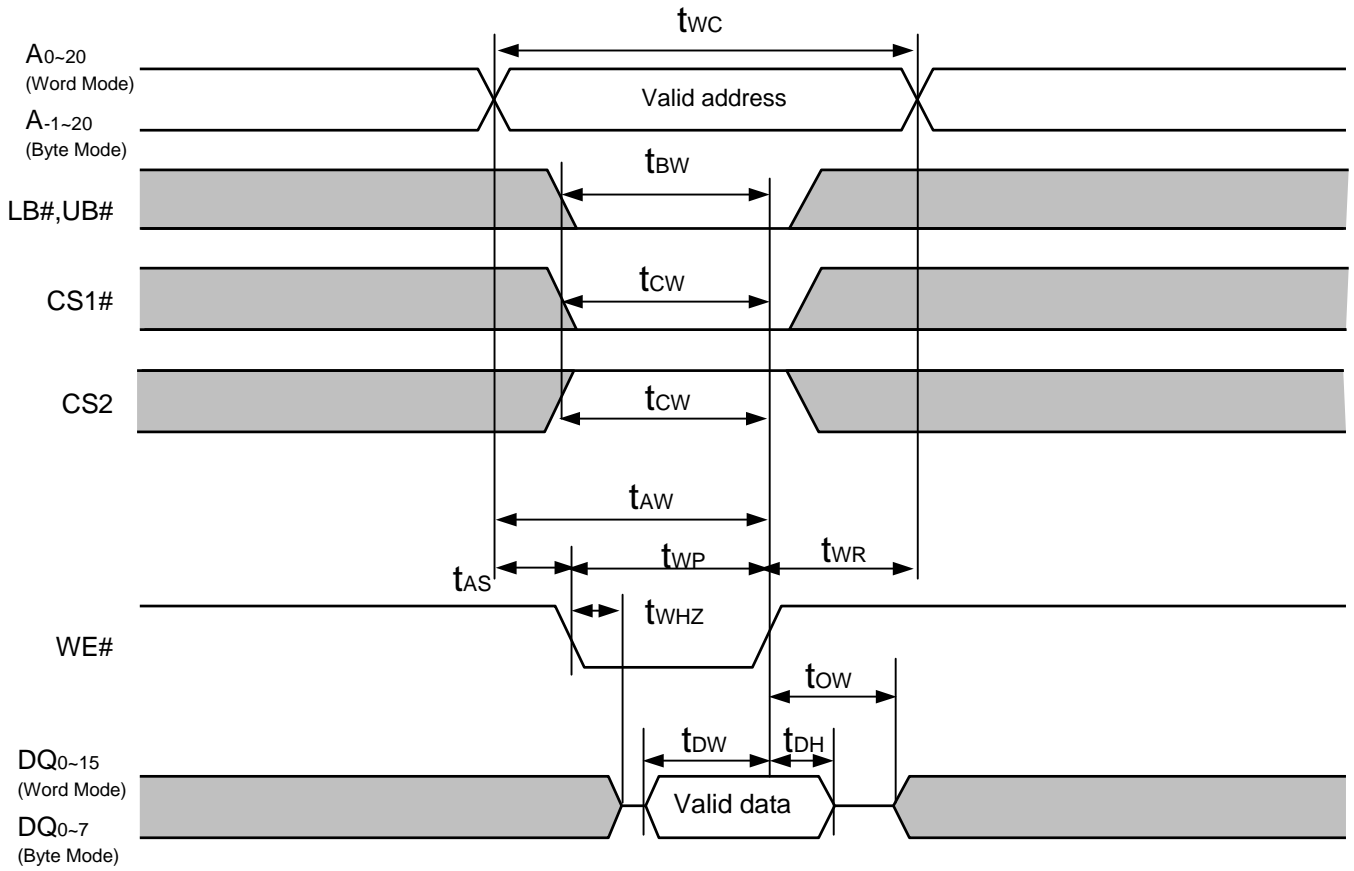
Timing Waveform

Read Timing Waveform



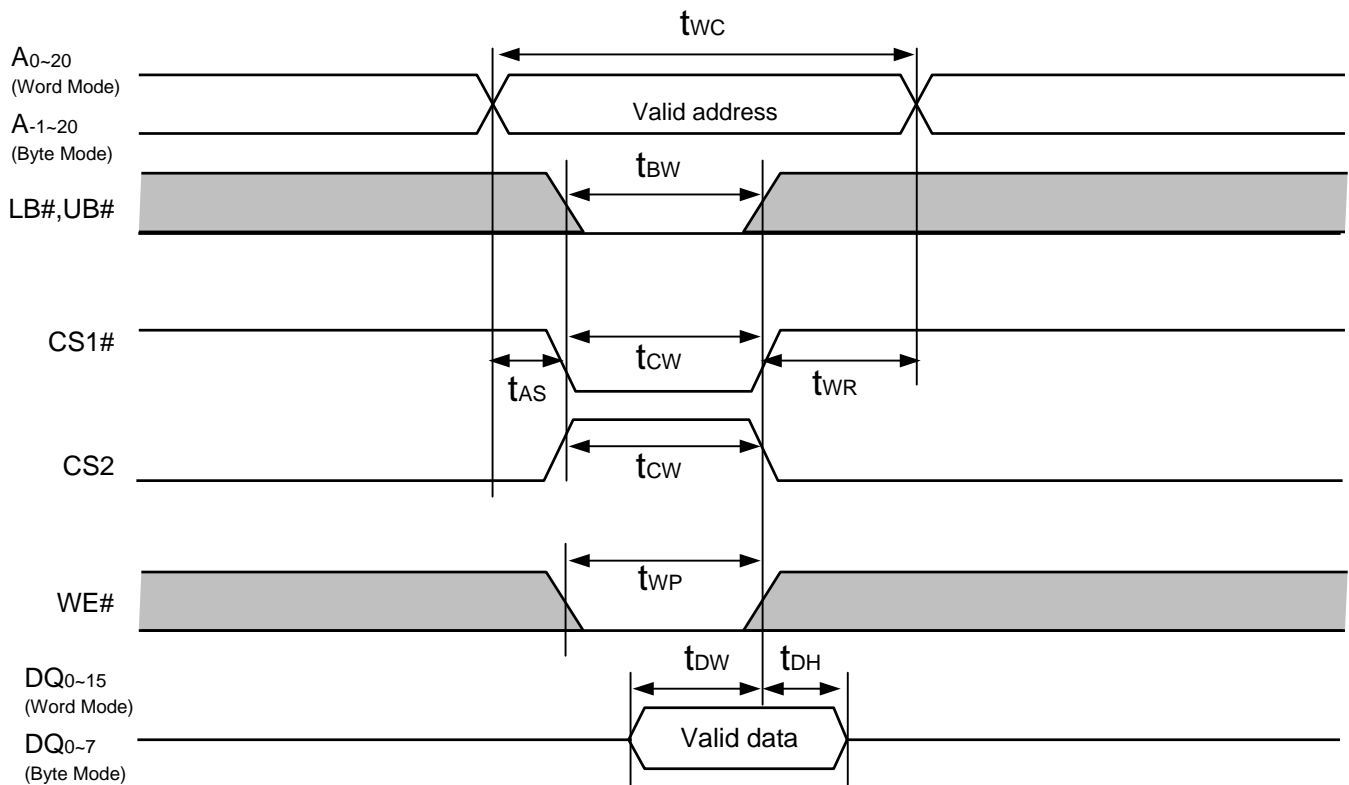
Note: Byte Mode is supported by only 52-pin μ SOP type. $BYTE\# \geq V_{CC}-0.2V$ or $BYTE\# \leq 0.2V$

Write Timing Waveform (1) (WE# CLOCK)



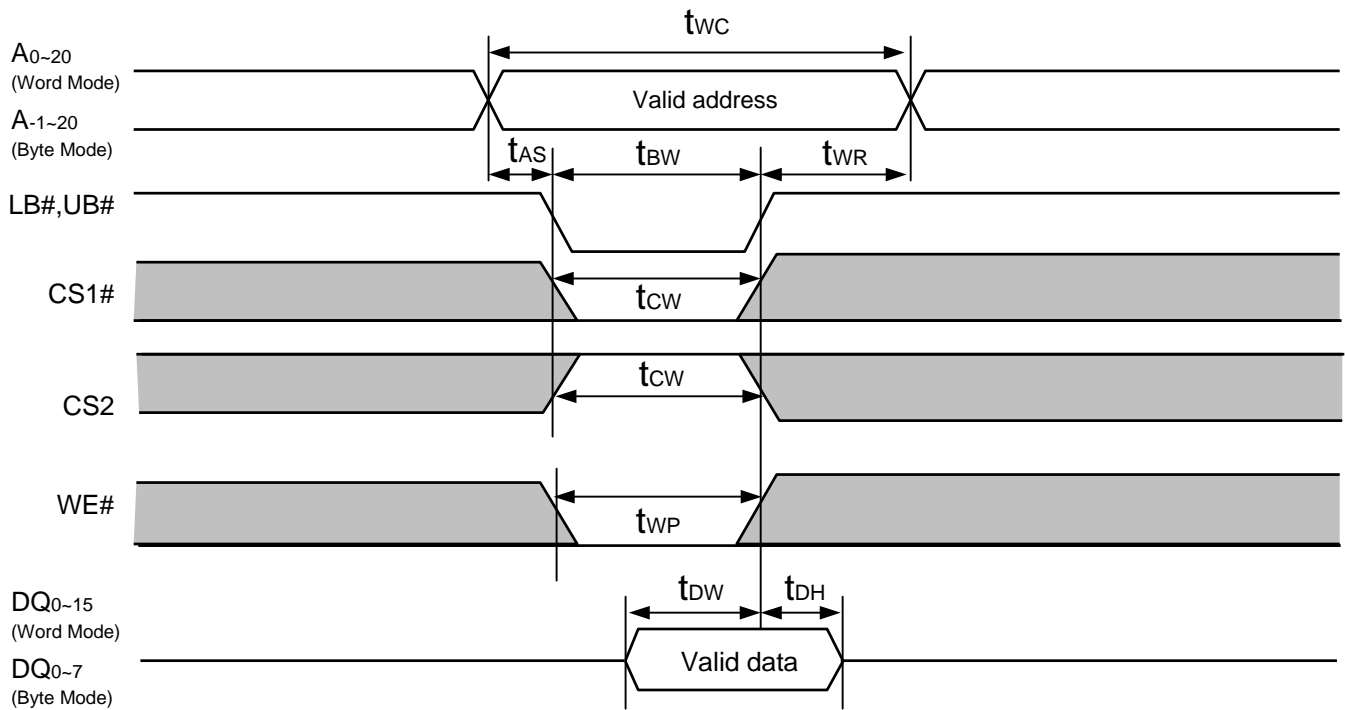
Note: Byte Mode is supported by only 52-pin μ TSOP type. $BYTE\# \geq V_{CC}-0.2V$ or $BYTE\# \leq 0.2V$

Write Timing Waveform (2) (CS1#, CS2 CLOCK, OE#=VIH)



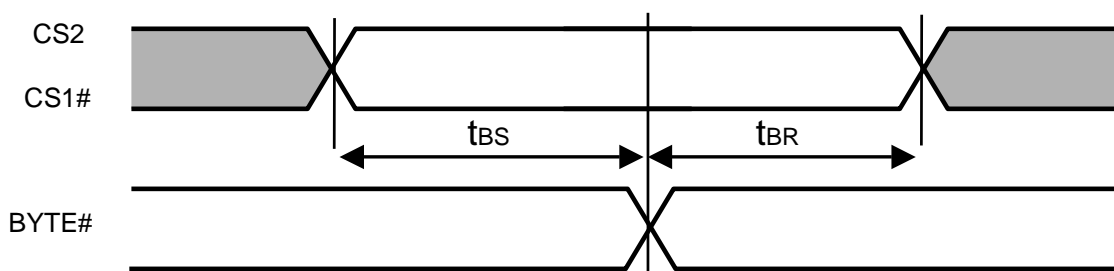
Note: Byte Mode is supported by only 52-pin μ TSSOP type. $BYTE\# \geq V_{CC}-0.2V$ or $BYTE\# \leq 0.2V$

Write Timing Waveform (3) (LB#,UB# CLOCK, OE#=VIH)



Note: Byte Mode is supported by only 52-pin μ SOP type. $BYTE\# \geq V_{CC}-0.2V$ or $BYTE\# \leq 0.2V$

BYTE# Timing Waveform

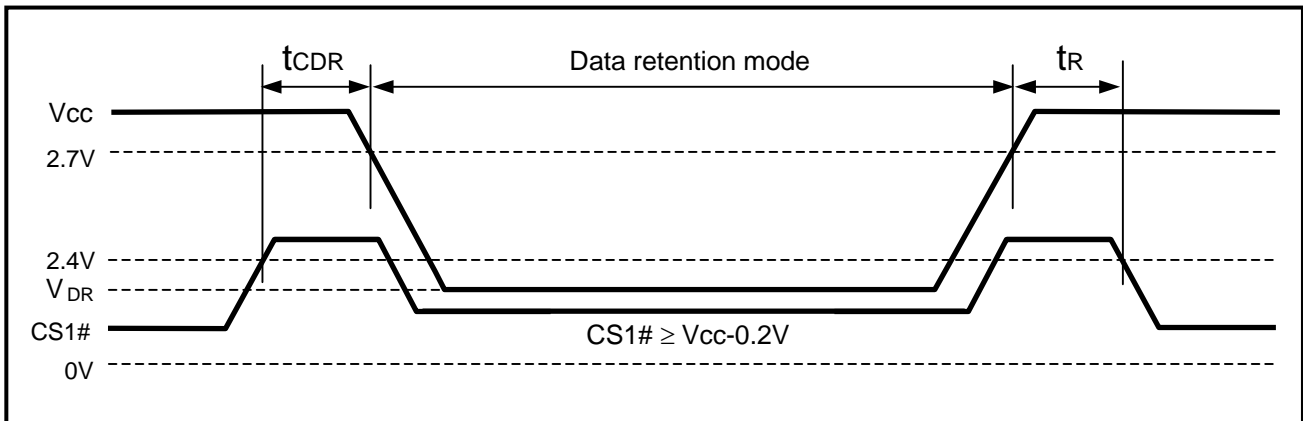


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|---------------------------------------|
| Data Retention Characteristics |
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| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test conditions*3,4 | |
|--------------------------------------|-------------------|------|------|------|------|--|--|
| Vcc for data retention | V _{DR} | 2.0 | - | 3.6 | V | V _{in} ≥ 0V, BYTE# ≥ V _{cc} -0.2V or BYTE# ≤ 0.2V (1) 0V ≤ CS2 ≤ 0.2V or (2) CS2 ≥ V _{cc} -0.2V, CS1# ≥ V _{cc} -0.2V or (3) LB# = UB# ≥ V _{cc} -0.2V, CS2 ≥ V _{cc} -0.2V, CS1# ≤ 0.2V | |
| Data retention current | I _{CCDR} | - | 4 *1 | 12 | μA | ~+25°C | V _{cc} =3.0V, V _{in} ≥0V, BYTE# ≥ V _{cc} -0.2V or BYTE# ≤ 0.2V (1) 0V ≤ CS2 ≤ 0.2V or (2) CS2 ≥ V _{cc} -0.2V, CS1# ≥ V _{cc} -0.2V or (3) LB# =UB# ≥V _{cc} -0.2V, CS2 ≥ V _{cc} -0.2V, CS1# ≤ 0.2V Average value |
| | | - | 7 *2 | 24 | μA | ~+40°C | |
| | | - | - | 50 | μA | ~+70°C | |
| | | - | - | 80 | μA | ~+85°C | |
| Chip deselect to data retention time | t _{CDR} | 0 | - | - | ns | See retention waveform | |
| Operation recovery time | t _R | 5 | - | - | ms | | |

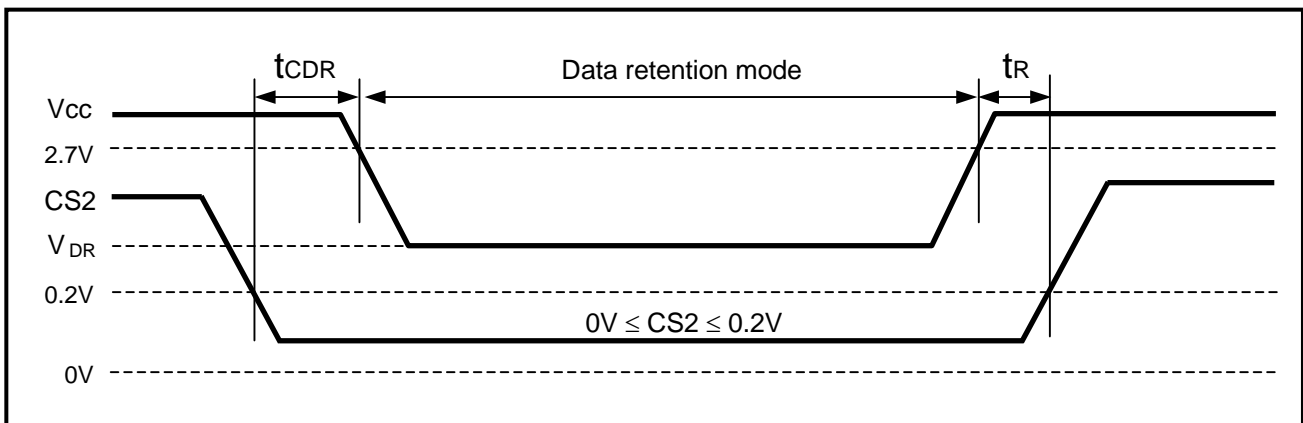
- Note 1. Typical parameter indicates the value for the center of distribution at V_{cc}=3.0V (T_a= 25°C) and not 100% tested.
 2. Typical parameter indicates the value for the center of distribution at V_{cc}=3.0V (T_a= 40°C) and not 100% tested.
 3. BYTE# pin is supported by only 52-pin μTSOP type.
 4. Also CS2 controls address buffer, WE# buffer, CS1# buffer, OE# buffer, LB#, UB# buffer and Din buffer. If CS2 controls data retention mode, V_{in} levels (address, WE#, OE#, CS1#, LB#, UB#, I/O) can be in the high impedance state. If CS1# controls data retention mode, CS2 must be CS2 ≥ V_{cc}-0.2V or 0V ≤ CS2 ≤ 0.2V. The other input levels (address, WE#, OE#, CS1#, LB#, UB#, I/O) can be in the high impedance state.

Low Vcc Data Retention Timing Waveform (1) (CS1# Controlled)



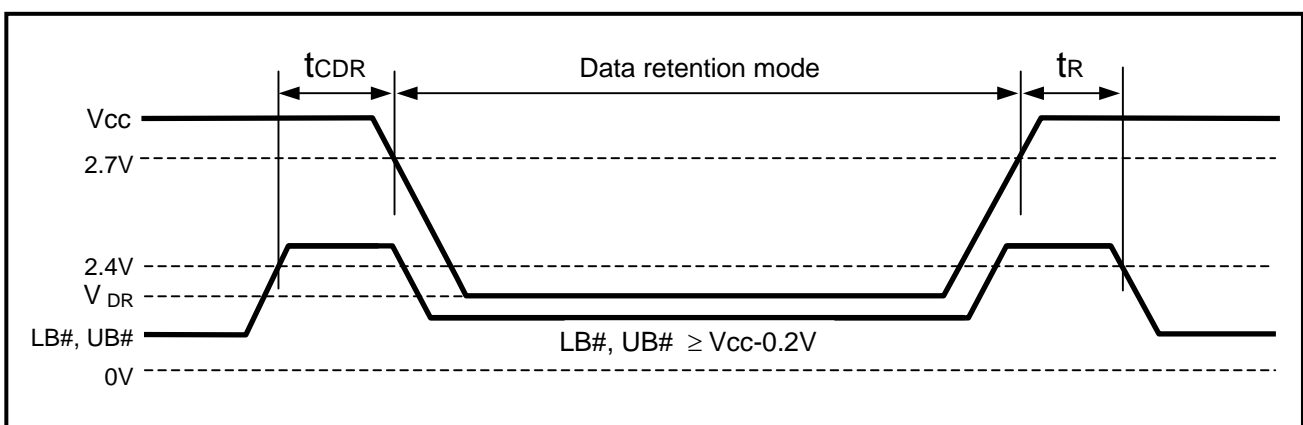
Note: BYTE# pin is supported by only 52-pin μ TSOP type. BYTE# \geq Vcc-0.2V or BYTE# \leq 0.2V

Low Vcc Data Retention Timing Waveform (2) (CS2 Controlled)



Note: BYTE# pin is supported by only 52-pin μ TSOP type. BYTE# \geq Vcc-0.2V or BYTE# \leq 0.2V

Low Vcc Data Retention Timing Waveform (3) (LB#, UB# Controlled)



Note: BYTE# pin is supported by only 52-pin μ TSOP type. BYTE# \geq Vcc-0.2V or BYTE# \leq 0.2V

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To our customers,

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April 1st, 2010
Renesas Electronics Corporation

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